



Universidad  
de Valparaíso  
C H I L E

# Transductores resistivos

Mediciones Biomédicas 2024

Ingeniería Civil Biomédica

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# Tipos de transductores

## Resistivos

Capacitivos

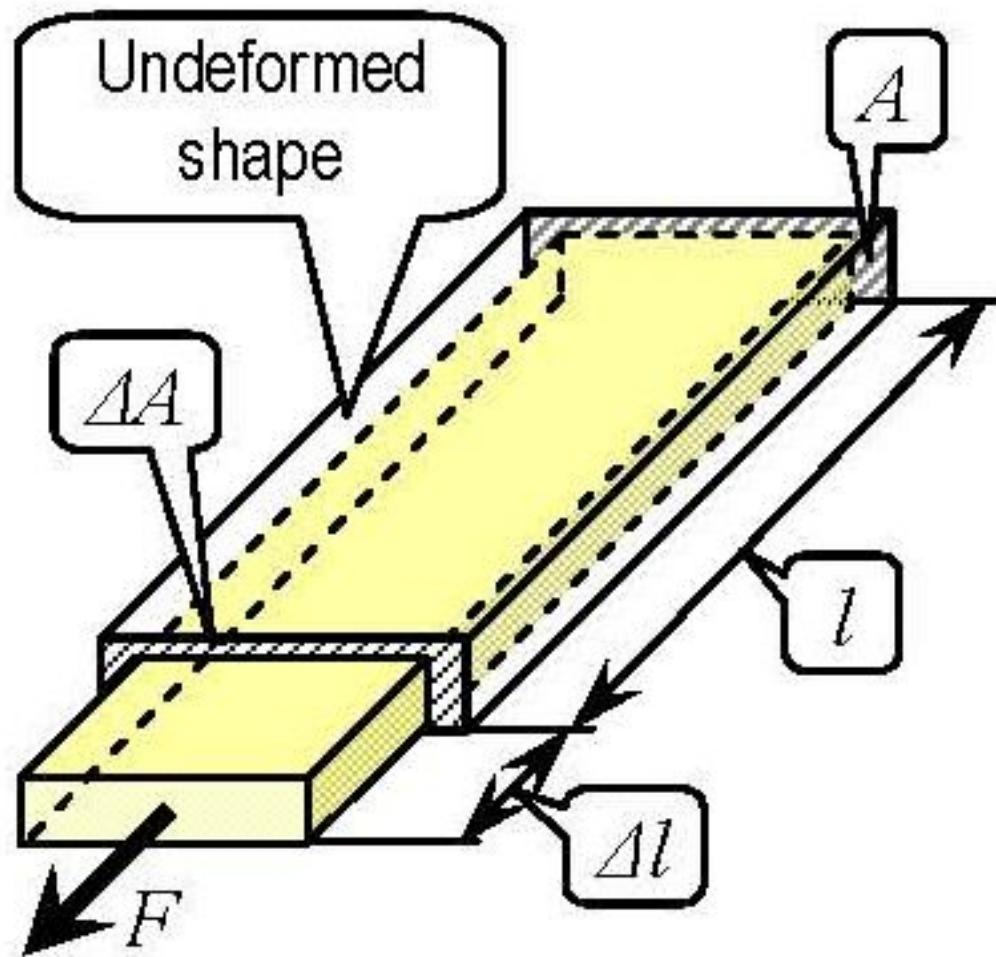
Piezoeléctricos

Inductivos/magnéticos

Térnicos

Radiación/ópticos

Electroquímicos (Cap. 4)



## T de R variable.

cuatro clases.

- 1) R cambia en función de las dimensiones físicas del T.
- 2) R cambia en función de la temperatura.
- 3) " sliding contact devices "
- 4) T hechos con semiconductores.

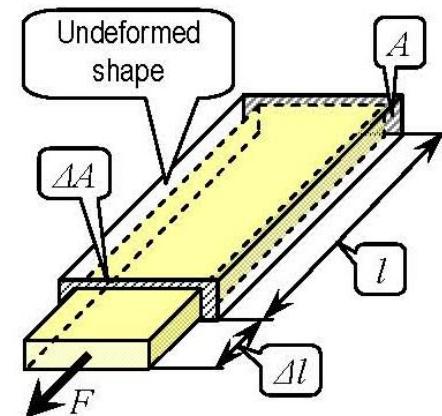
→ 1) R cambia en función de las dimensiones  
La resistencia de un conductor  
de geometría uniforme está  
dado por:

$$R \text{ (ohms)} = \rho l / A$$

$\rho$ : Resistencia específica ( $\Omega m$ )

$l$ : largo en metros

$A$ : Área transversal en  $m^2$ .



Si una de las cantidades  $\ell$ ,  $l$  ó  $A$  cambia entonces  $R$  cambia. Para estudiar esto se expresa el diferencial:

$$dR = \frac{(\ell dl + l d\ell) A - \ell l dA}{A^2}$$

Definamos Ahora:

$$A = k s^2$$

donde  $k$  es una constante de proporcionalidad  
y  $s$  es la dimensión longitudinal.

→ Si  $A$  representa un cuadrado  $k = 1$

→ Si  $A$  representa un círculo  $k = \frac{\pi}{4}$

$$dA = d(k s^2) = 2 k s d s$$

y por tanto

$$dR = \frac{k s^2 (pd\ell + \ell dp) - 2k s \ell d s}{(k s^2)^2}$$

Para un ane transversal rectangular:

$$\frac{dR}{R} = \left( \frac{A(\ell d\ell + l d\ell) - pl dA}{A^2} \right) \left( \frac{A}{pl} \right)$$

$$= \frac{d\ell}{l} + \frac{dl}{l} - \frac{dA}{A}$$

$$= \frac{d\ell}{l} + \frac{dl}{l} - \frac{2ds}{S}$$

ó

$$\frac{\frac{dR}{R}}{\frac{d\ell}{l}} = 1 + \frac{d\ell/l}{d\ell/l} - 2 \frac{ds/S}{d\ell/l}$$

ó

$$\frac{\frac{dR/R}{E_a}}{E_a} = 1 + \frac{d\ell/\ell}{E_a} - 2 \frac{\frac{E_L}{E_a}}{\underline{d\ell/l}}$$

$$= 1 + \frac{d\ell/\ell}{d\ell/l} + 2 \underline{\mu}$$

dónde  $\epsilon_a$ : es el stress axial sobre el conducto ( $\text{m/m}$ )

$\epsilon_L$ : stress lateral ( $\text{m/m}$ )

$\mu$ : razón de Poisson

Este principio es empleado por los galgos extensiométricas  
(strain gauges).

El factor  $dR/R/\epsilon_a$  se conoce como factor de galga.

# Galgas extensiométricas, GE (strain gauges)

- Los parámetros característicos de las GE son:
  - Resistencia nominal R.
  - Factor de galga (gauge factor) G.
  - Coeficiente de temperatura TK.

$$G = \frac{\frac{\Delta R}{R}}{\frac{\Delta \ell}{\ell}} \quad TK = \frac{\frac{\Delta R}{R}}{\Delta T}$$

**Table 2.1 Properties of Strain-gage Materials**

| <b>Material</b>         | <b>Composition (%)</b>                                                       | <b>Gage Factor</b> | <b>Temperature Coefficient of Resistivity (<math>^{\circ}\text{C}^{-1} - 10^{-5}</math>)</b> |
|-------------------------|------------------------------------------------------------------------------|--------------------|----------------------------------------------------------------------------------------------|
| Constantan<br>(advance) | $\text{Ni}_{45}, \text{Cu}_{55}$                                             | 2.1                | $\pm 2$                                                                                      |
| Isoelastic              | $\text{Ni}_{36}, \text{Cr}_8$<br>$(\text{Mn, Si, Mo})_4$<br>$\text{Fe}_{52}$ | 3.52 to 3.6        | +17                                                                                          |
| Karma                   | $\text{Ni}_{74}, \text{Cr}_{20}, \text{Fe}_3$<br>$\text{Cu}_3$               | 2.1                | +2                                                                                           |
| Manganin                | $\text{Cu}_{84}, \text{Mn}_{12}, \text{Ni}_4$                                | 0.3 to 0.47        | $\pm 2$                                                                                      |
| Alloy 479               | $\text{Pt}_{92}, \text{W}_8$                                                 | 3.6 to 4.4         | +24                                                                                          |
| Nickel                  | Pure                                                                         | -12 to -20         | 670                                                                                          |
| Nichrome V              | $\text{Ni}_{80}, \text{Cr}_{20}$                                             | 2.1 to 2.63        | 10                                                                                           |
| Silicon                 | ( <i>p</i> type)                                                             | 100 to 170         | 70 to 700                                                                                    |
| Silicon                 | ( <i>n</i> type)                                                             | -100 to -140       | 70 to 700                                                                                    |
| Germanium               | ( <i>p</i> type)                                                             | 102                |                                                                                              |
| Germanium               | ( <i>n</i> type)                                                             | -150               |                                                                                              |

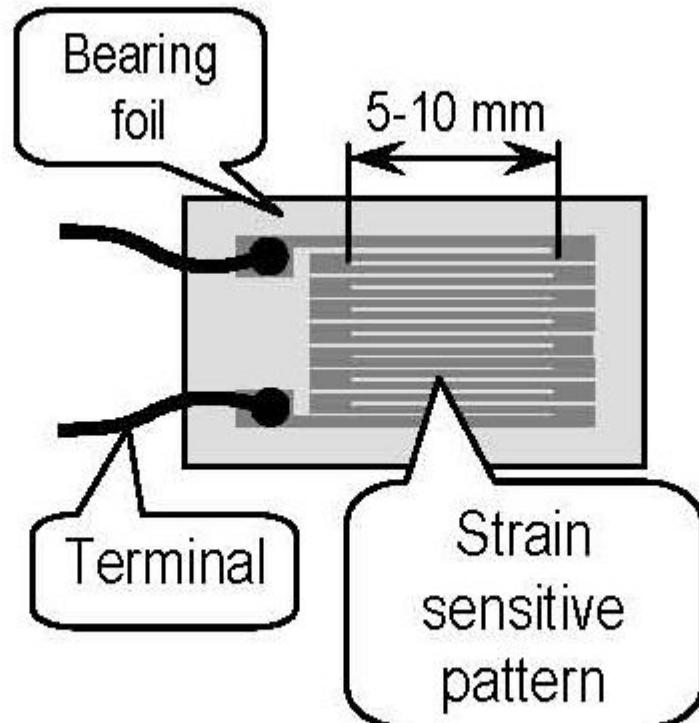
# Galgas extensiométricas, GE (strain gauges)

## Estructura típica.

Se forma una tira conductora larga y delgada - antiguamente enlazada (bonded), actualmente depositada sobre una capa aislante (unbonded strain gages) - siguiendo un patrón "zig-zag" de líneas paralelas.

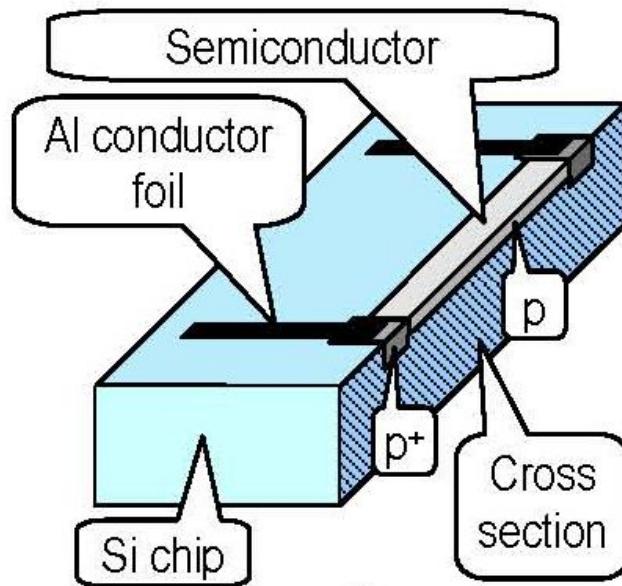
La sensibilidad de la forma zig-zag es mucho más alta en la dirección de las líneas paralelas.

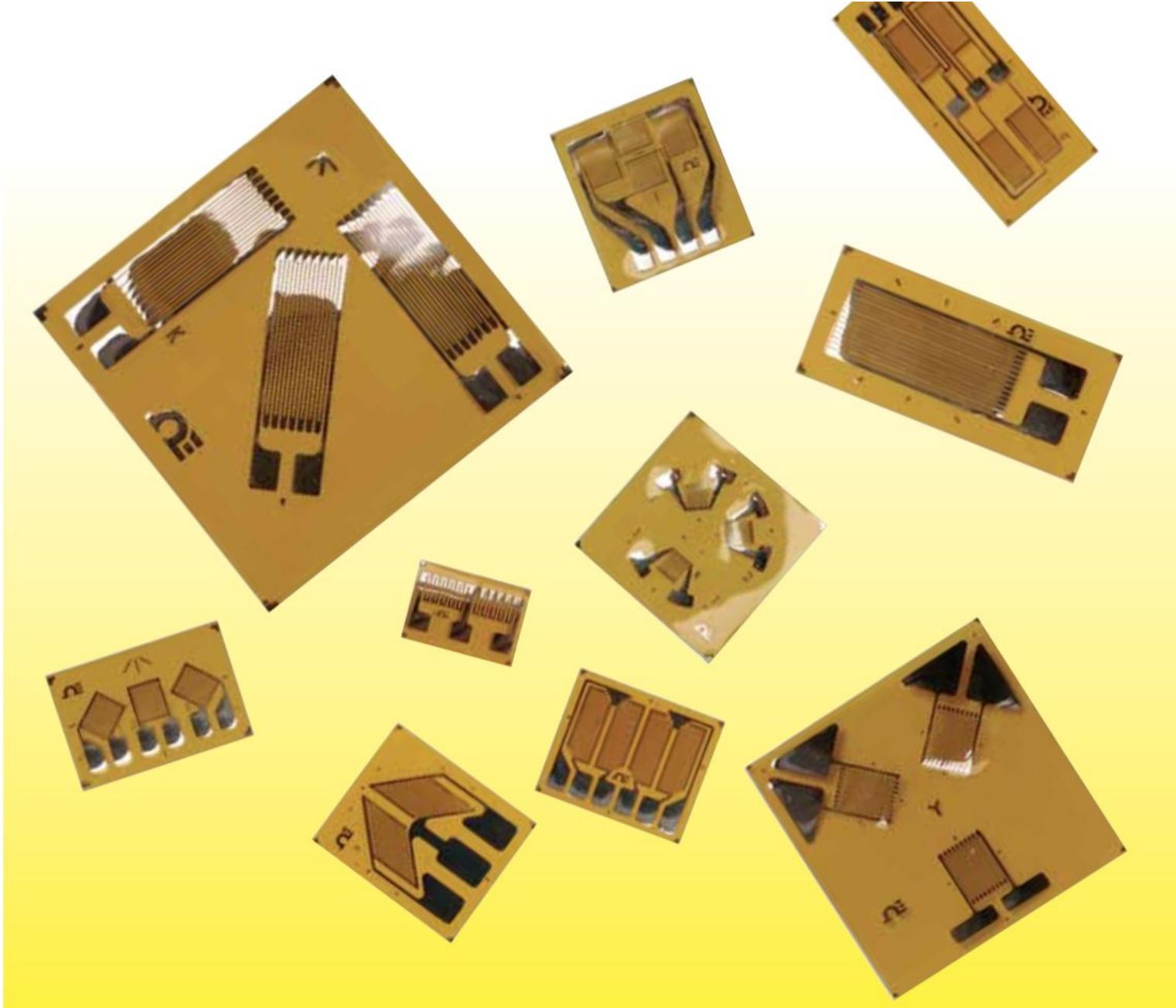
La fuerza o flexión a medir determina la extensión relativa de  $\Delta l / l$ .



# Galgas extensiométricas, GE (strain gauges)

- Existen GE construidas con materiales semiconductores.
- Se les llama también piezoresistores.
- Tienen una mayor sensibilidad.
- No obstante, son más costosas, poseen coeficientes de temperatura mayores y son más frágiles.





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... 18"(L\*w); product name: pressure resistive strain  
gauge ...Gikfun BF350-3AA BF350 Precision Pressure Resistance Strain Gauge 350ohm for Arduino AE1134  
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Strain limit: 2.0%FORCE SENSING RESISTOR, 1.5 INCH SQUARE, 1oz-22LBS, 2 LEADS, 0.1 INCH SPACING  
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5

## Product Features

Strain limit: 2.0%

High precision resistance strain gauge / strain gauge / GAGE/ full bridge (for pressure / load sensor)  
by quickbuying

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Product Description  
... High precision resistance strain gauge / strain  
gauge / GAGE/ full ...

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# Galgas extensiométricas, GE (strain gauges)

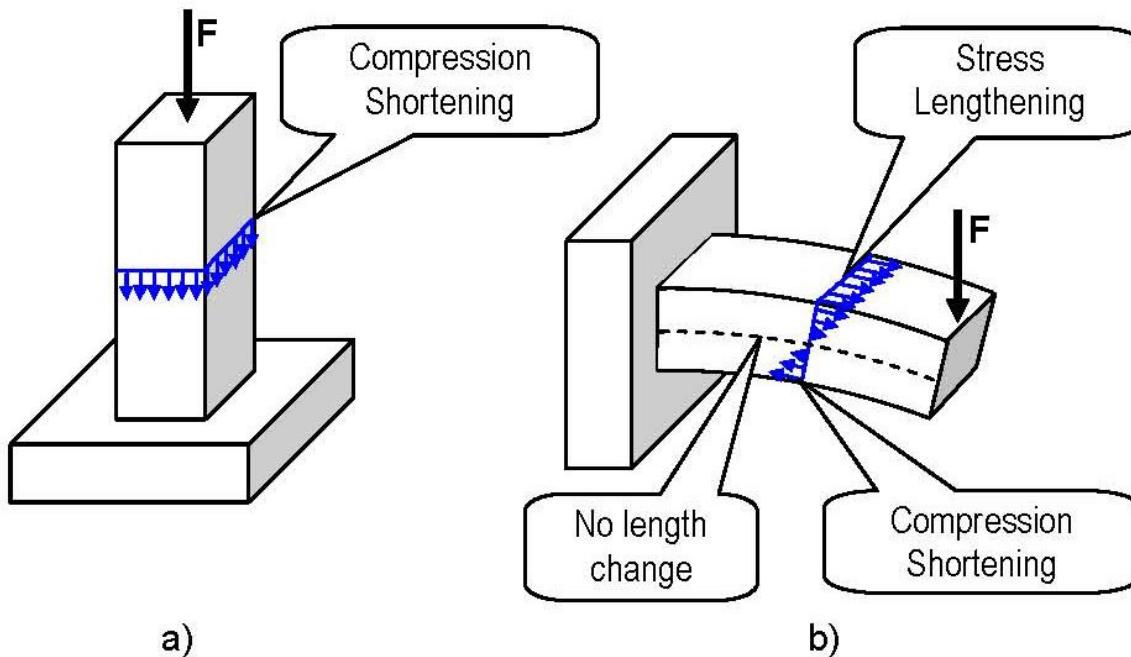
Características generales:

- La resistividad de las GE metálicas no cambia durante el stress ( $\Delta\rho\approx0$ ).
  - Esto resulta en valores de G cercanos a 2.
- La resistividad de las GE basadas en semiconductores cambia significativamente durante el stress.
  - $\Delta\rho/\rho \gg 1$ .
  - A esto se le llama efecto piezo-resistivo.
- Las GE basadas en semiconductores son pequeñas, y a menudo se comercializan en circuitos integrados que incluyen los amplificadores necesarios.
  - Basado en esto, existen sensores de presión y aceleración integrados.

# Galgas extensiométricas, GE (strain gauges)

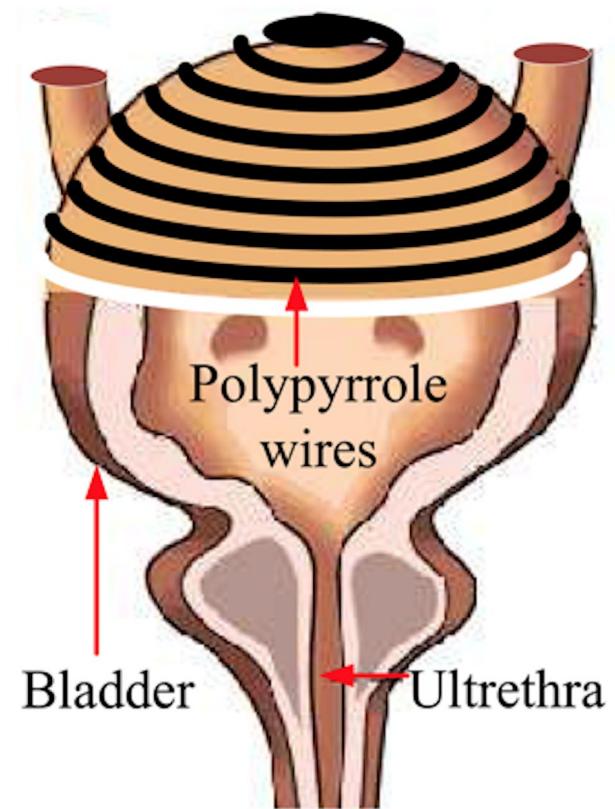
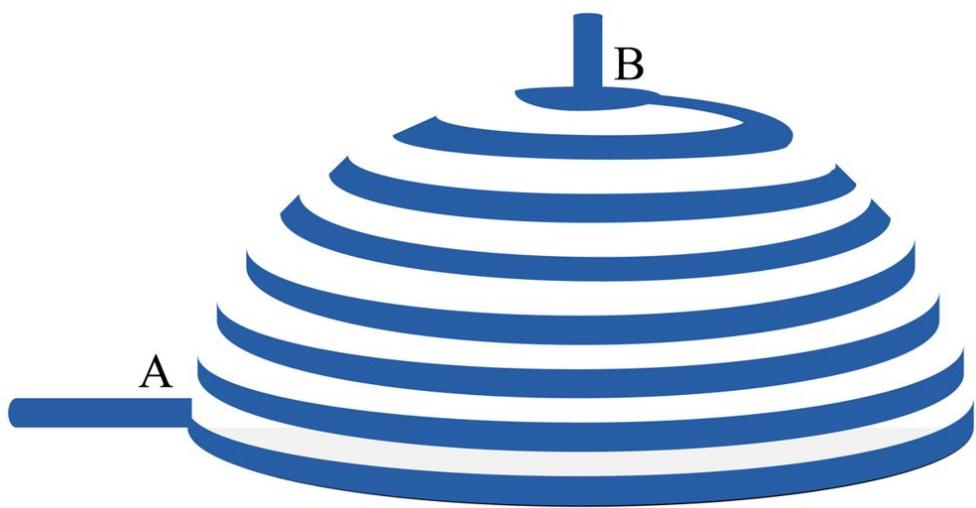
Características generales:

- Las GE están típicamente unidas a objetos.



**Deformations to be measured (exaggerated). Deformation of a stressed or compressed object has similar deformation on each side (a). Bending of the object results in both stress and compression at the same time (b).**

Rajagopalan S., Sawan M., Ghafar-Zadeh E., Savadogo O. & Chodavarapu V.P., 2008. A polypyrrole-based strain sensor dedicated to measure bladder volume in patients with urinary dysfunction. Sensors. 8, 5081-5095.



# **Investigation of arterial obstruction using a mercury-in-rubber strain gauge**

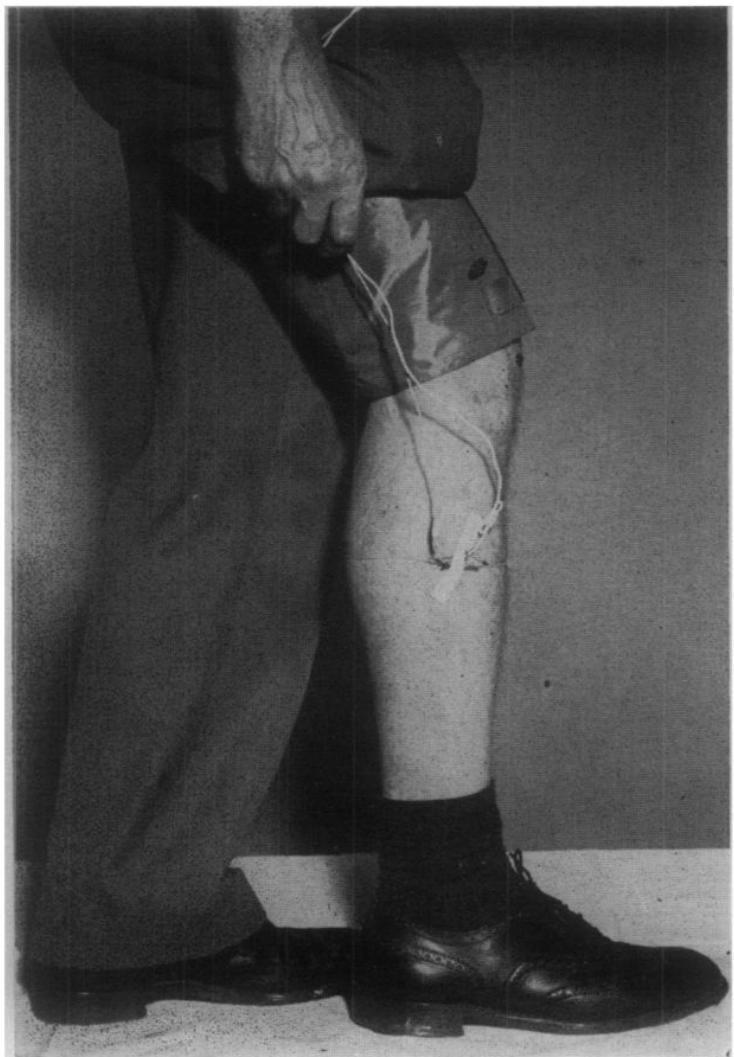
*H. Edward Holling, M.D., F.R.C.P. (London)\**

*H. Christine Boland, B.S.\*\**

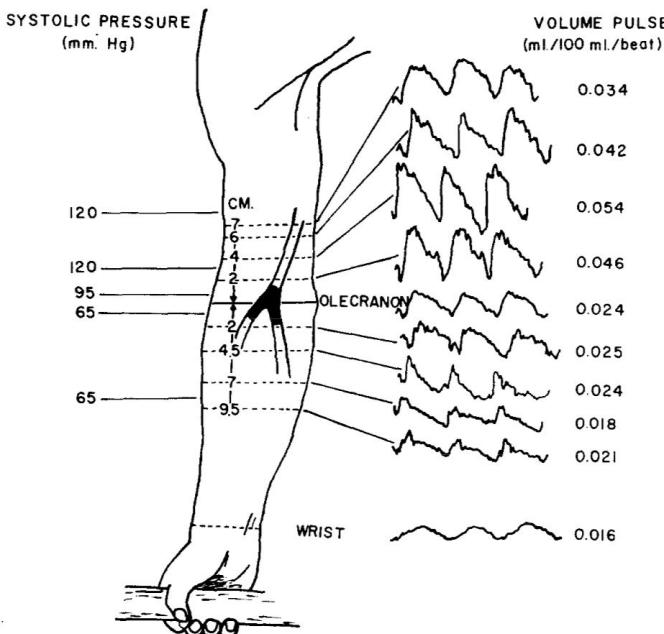
*Ellier Russ, D.S.C.\*\*\**

*Philadelphia, Pa.*

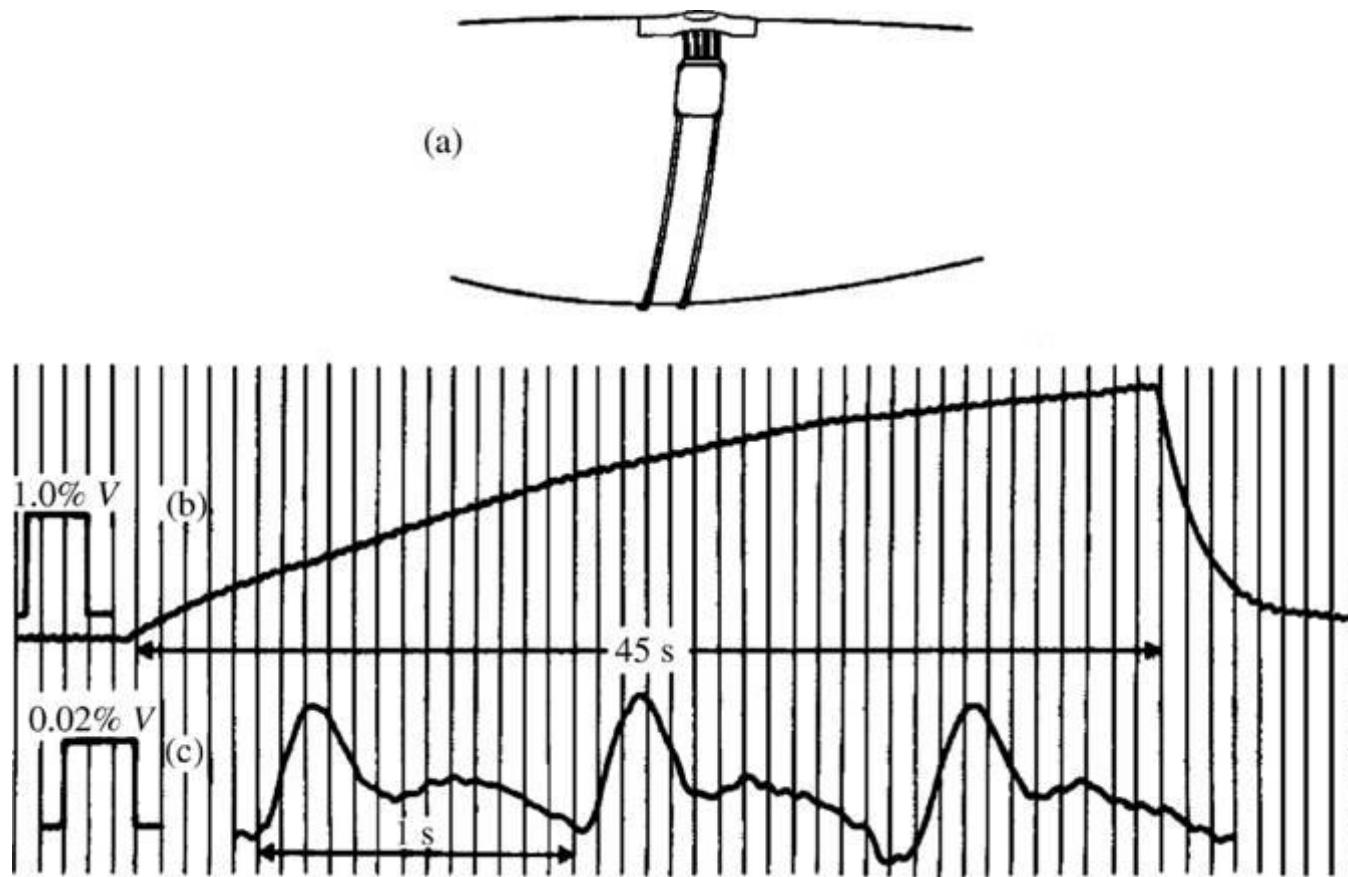
**American Heart Journal, Volume 62,  
Issue 2, August 1961, Pages 194-205.**



**Fig. 1.** Strain gauge applied to calf for exercise test.



**Fig. 4.** Systolic pressure (*left*) and volume pulse (*right*) in a case of embolus to the bifurcation of the right brachial artery. The figures on the arm indicate the distance in centimeters from the point of the olecranon

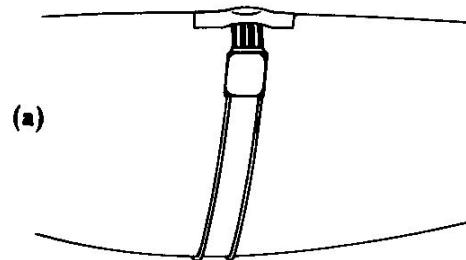


**Figure 2.6 Mercury-in-rubber strain-gage plethysmography** (a) Four-lead gage applied to human calf, (b) Bridge output for venous-occlusion plethysmography. (c) Bridge output for arterial-pulse plethysmography. [Part (a) is based on D. E. Hokanson, D. S. Sumner, and D. E. Strandness, Jr., "An electrically calibrated plethysmograph for direct measurement of limb blood flow." 1975, BME-22, 25–29; used with permission of *IEEE Trans. Biomed. Eng.*, 1975, New York.]

# Elastic-Resistance Strain Gages

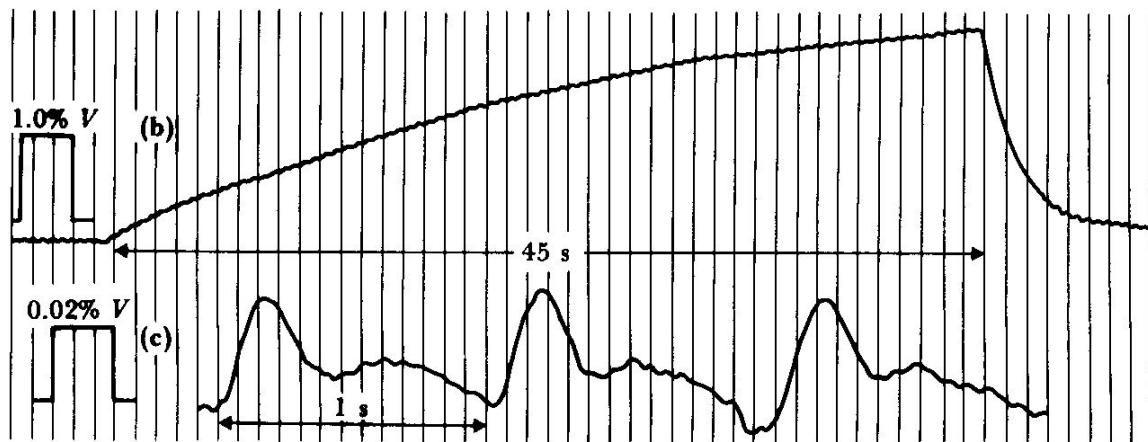
Extensively used in Cardiovascular and respiratory dimensional and volume determinations.

As the tube stretches, the diameter decreases and the length increases, causing the resistance to increase

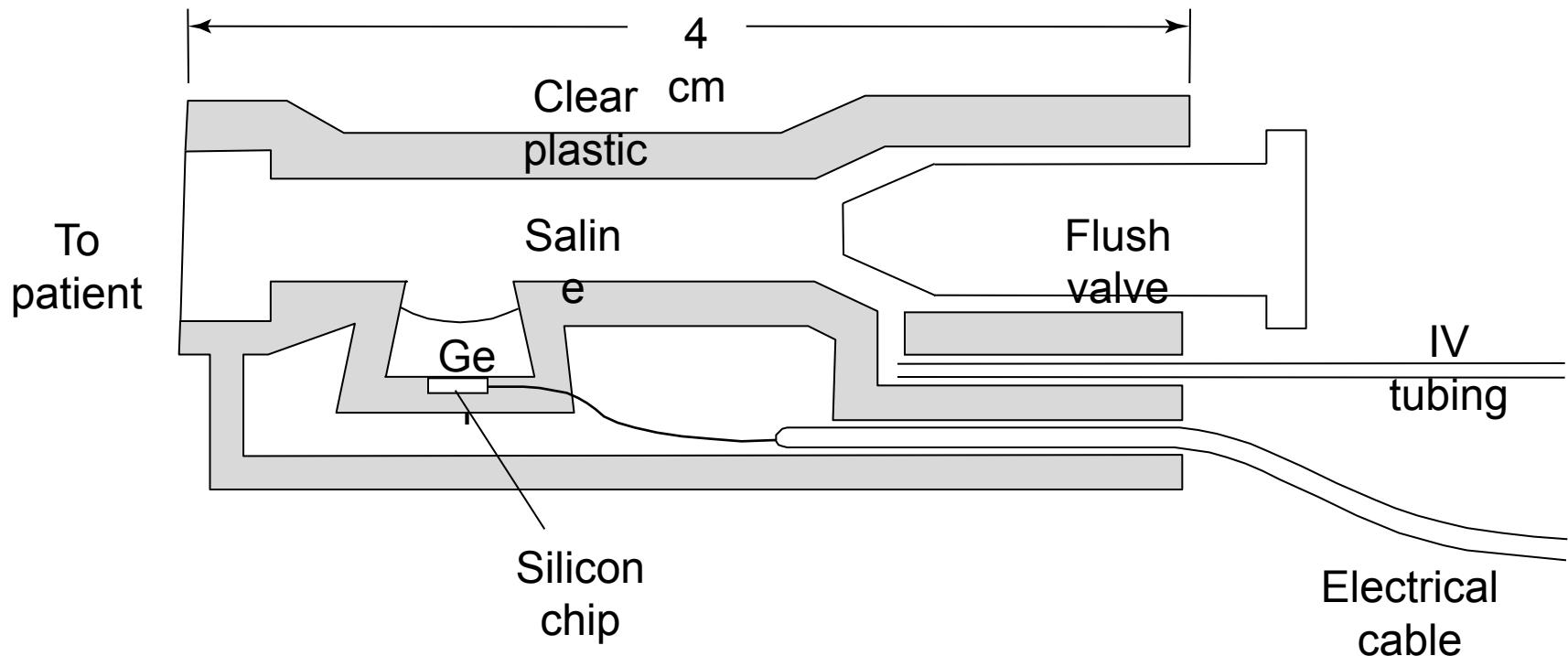


b) venous-occlusion plethysmography

c) arterial-pulse plethysmography



Filled with a conductive fluid (mercury, conductive paste, electrolyte solution).  
Resistance =  $0.02 - 2 \Omega/\text{cm}$ , linear within 1% for 10% of maximal extension



### **Isolation in a disposable blood-pressure sensor.**

Disposable blood pressure sensors are made of clear plastic so air bubbles are easily seen. Saline flows from an intravenous (IV) bag through the clear IV tubing and the sensor to the patient. This flushes blood out of the tip of the indwelling catheter to prevent clotting. A lever can open or close the flush valve. The silicon chip has a silicon diaphragm with a four-resistor Wheatstone bridge diffused into it. Its electrical connections are protected from the saline by a compliant silicone elastomer gel, which also provides electrical isolation. This prevents electric shock from the sensor to the patient and prevents destructive currents during defibrillation from the patient to the silicon chip.



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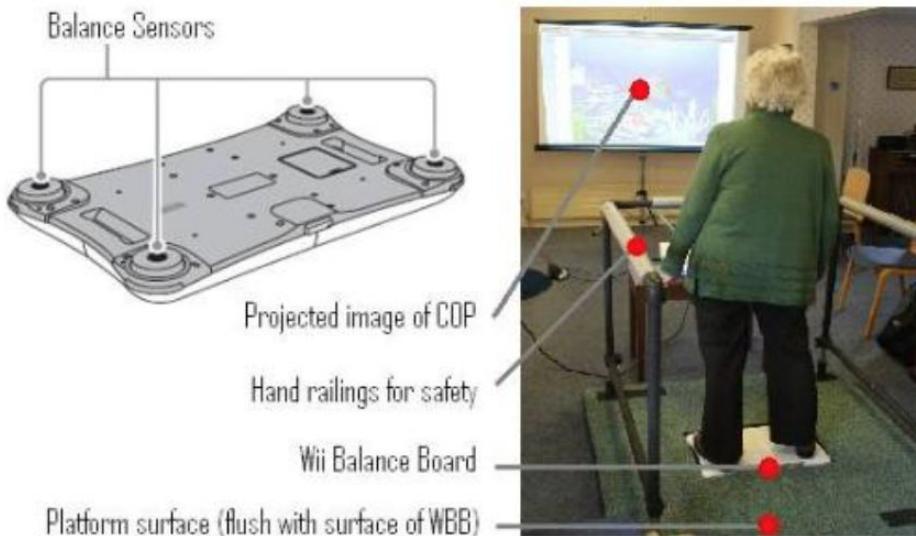
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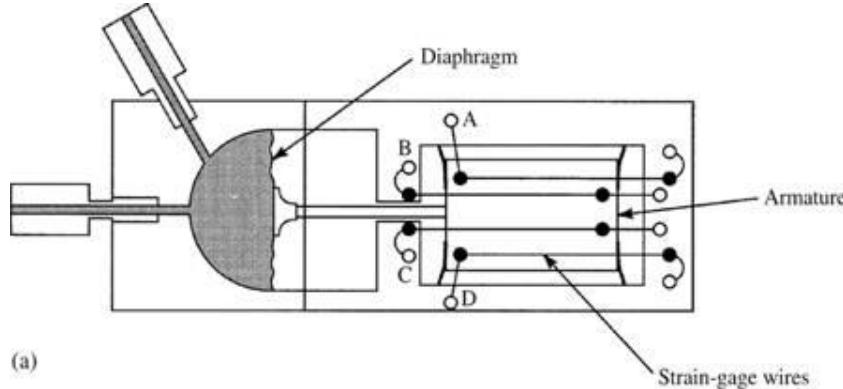
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## Interactive Movement Games

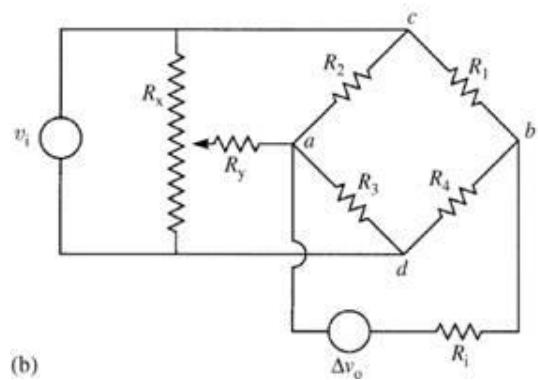
In collaboration with Dr Stuart Ferguson from the School of Electronics, Electrical Engineering and Computer Science, we have developed a way to interface the Nintendo Wii balance board with the virtual reality software 'Virtools'. By recording the bluetooth signal emitted from each pressure sensor embedded in the feet of the balance board, we can calculate the user's centre of pressure or the position of their balance. We then use this balance measure as the movement based controller in our virtual games environment (see [Young et al 2010](#) for details). This interface allows us to create adapted games and tests to train and assess balance in older adults and people with Parkinson's.



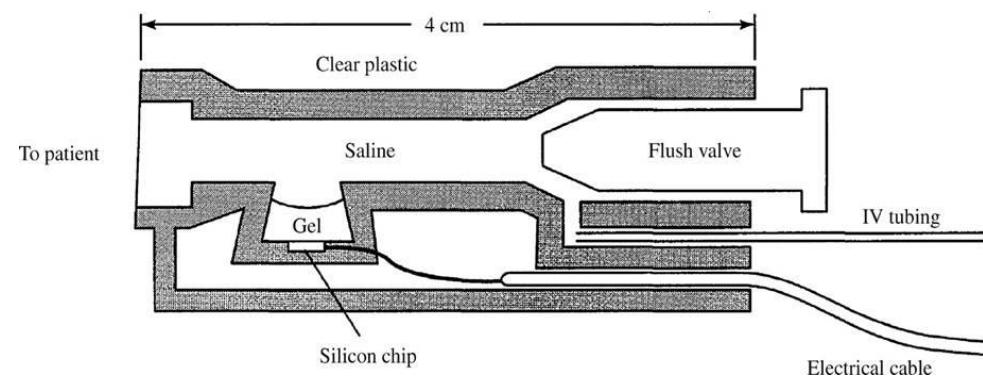
# Puente de Wheatstone



(a)



(b)

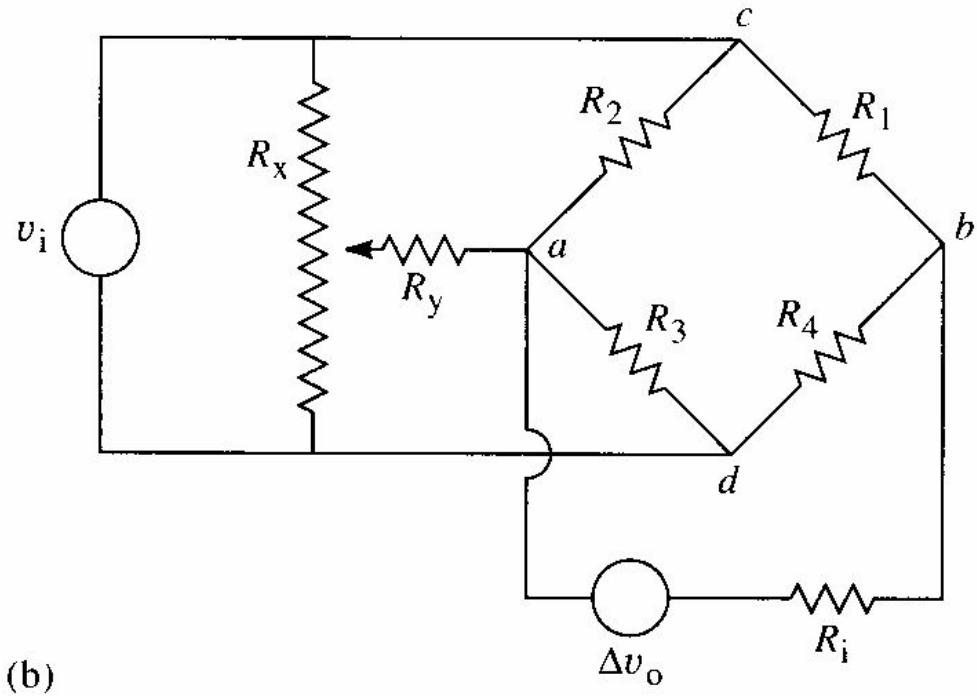


# Puente de Wheatstone

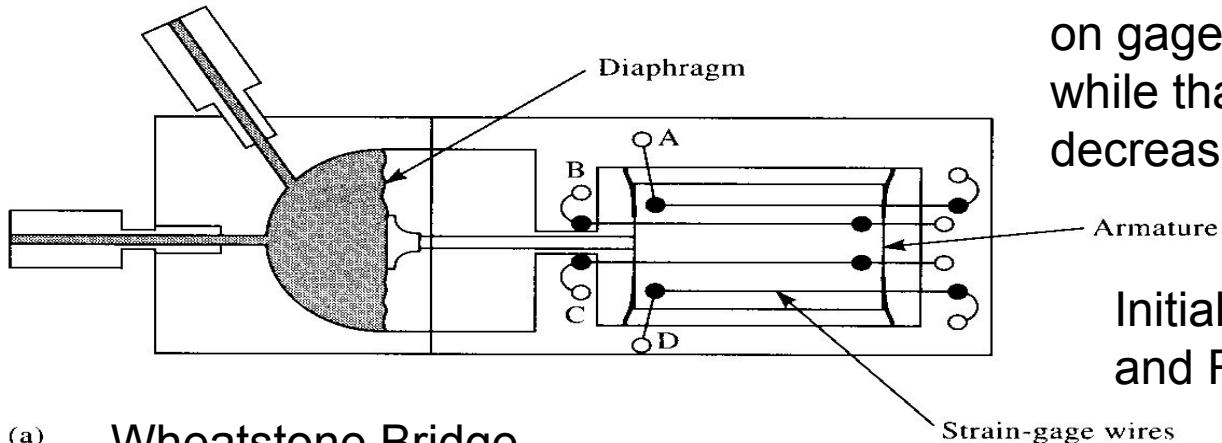
$\Delta v_o$  is zero when the bridge is balanced- that is when  $R_1 / R_2 = R_4 / R_3$

If all resistor has initial value  $R_0$  then if  $R_1$  and  $R_3$  increase by  $\Delta R$ , and  $R_2$  and  $R_4$  decreases by  $\Delta R$ , then

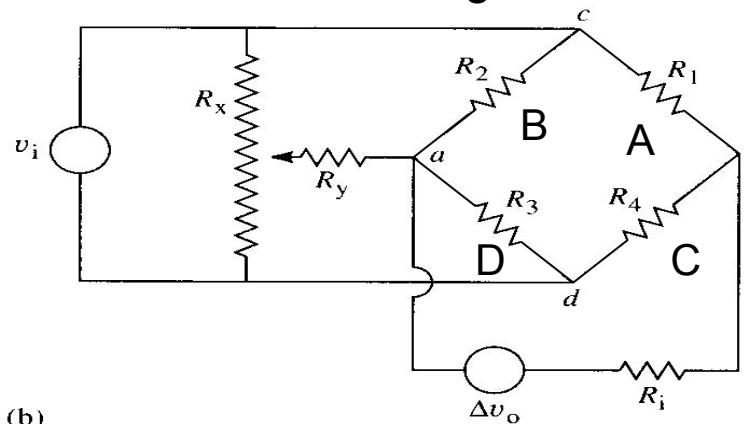
$$\Delta v_o = \frac{\Delta R}{R_0} v_i$$



## Unbonded strain gage:



(a) Wheatstone Bridge



(b)

With increasing pressure, the strain on gage pair **B** and **C** is increased, while that on gage pair **A** and **D** is decreased.

Initially before any pressure  $R_1 = R_4$  and  $R_3 = R_2$

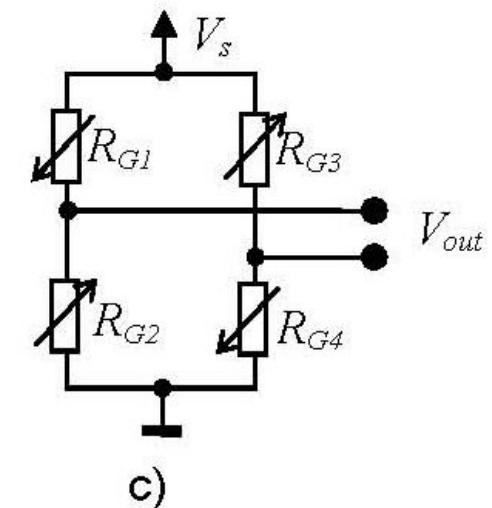
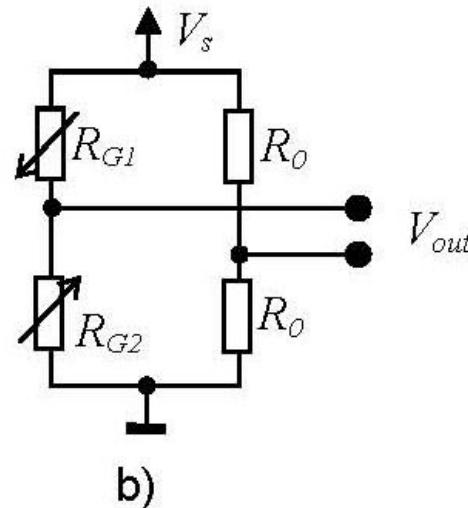
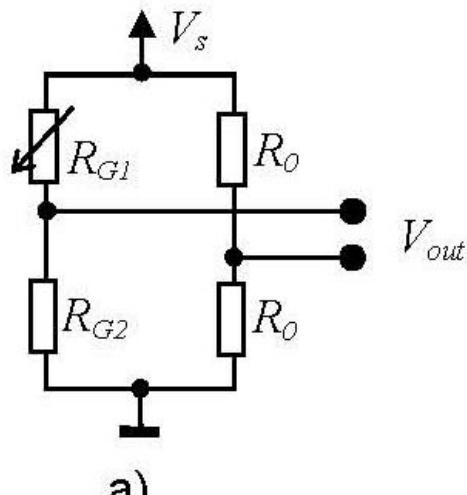
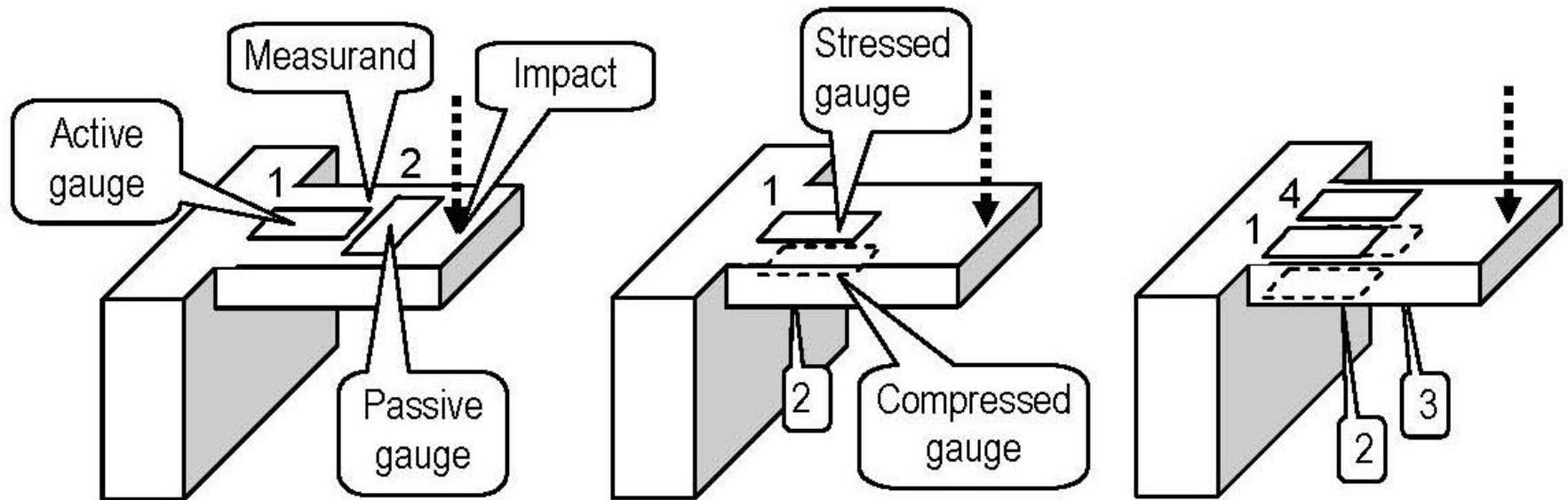
$$V_a = V_i \left( \frac{R_3}{R_2 + R_3} \right) \quad V_b = V_i \left( \frac{R_4}{R_1 + R_4} \right)$$

$$V_o = V_a - V_b = V_i \left( \frac{R_3}{R_2 + R_3} - \frac{R_4}{R_1 + R_4} \right)$$

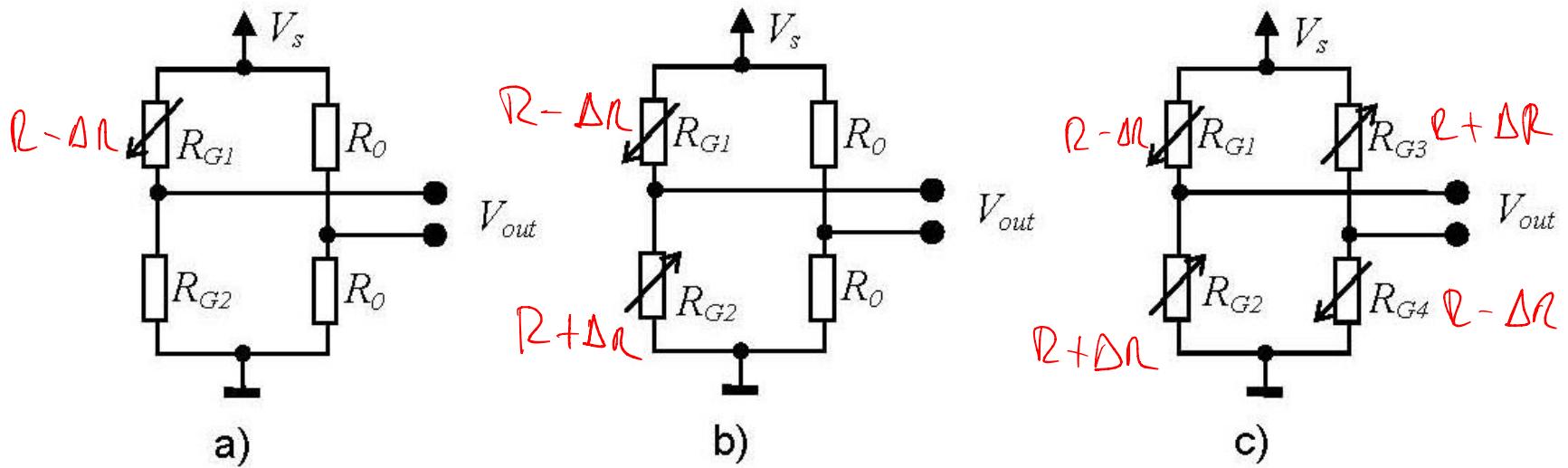
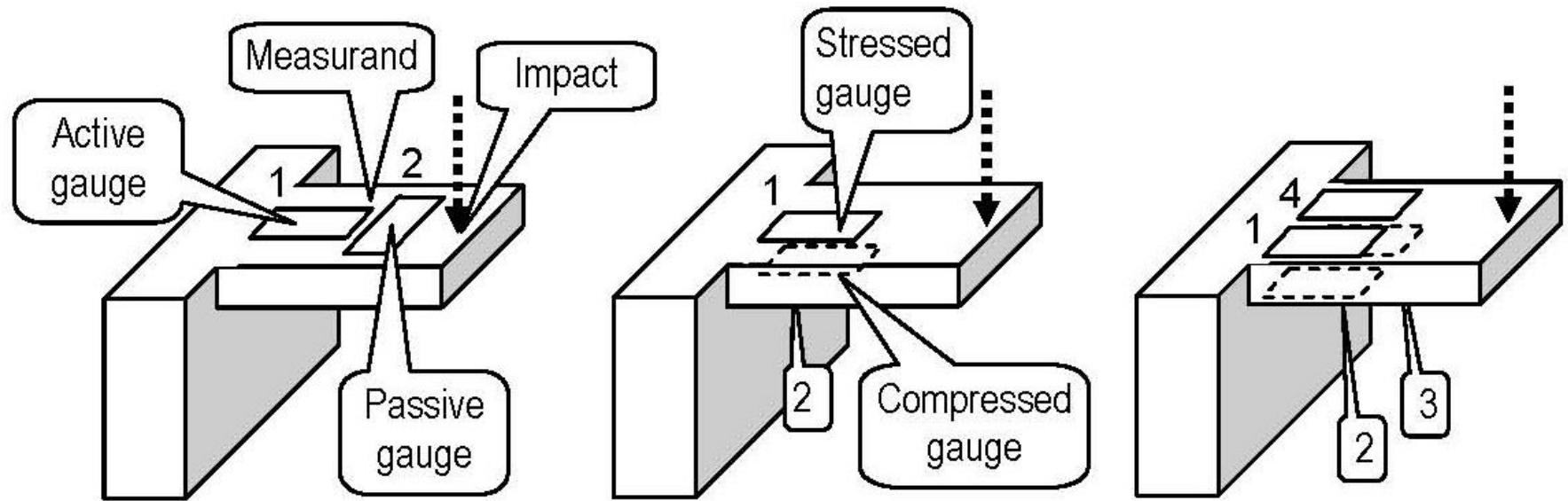
$$V_o = V_i \left( \frac{R_4(R_3 - R_2) + R_3(R_1 - R_4)}{(R_2 + R_3)(R_1 + R_4)} \right)$$

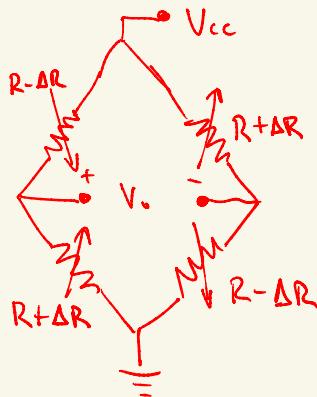
Fig. 2.2 legend:  $R_1 = A$ ,  $R_2 = B$ ,  $R_3 = D$ ,  $R_4 = C$

# Puente de Wheatstone



# Puente de Wheatstone





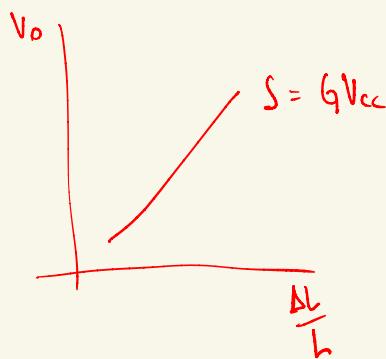
$$V_o = \left( \frac{R+\Delta R}{R+\Delta R + R-\Delta R} - \frac{R-\Delta R}{R-\Delta R + R+\Delta R} \right) V_{cc}$$

$$V_o = \frac{2\Delta R}{2R} V_{cc} = \frac{\Delta R}{R} V_{cc}$$

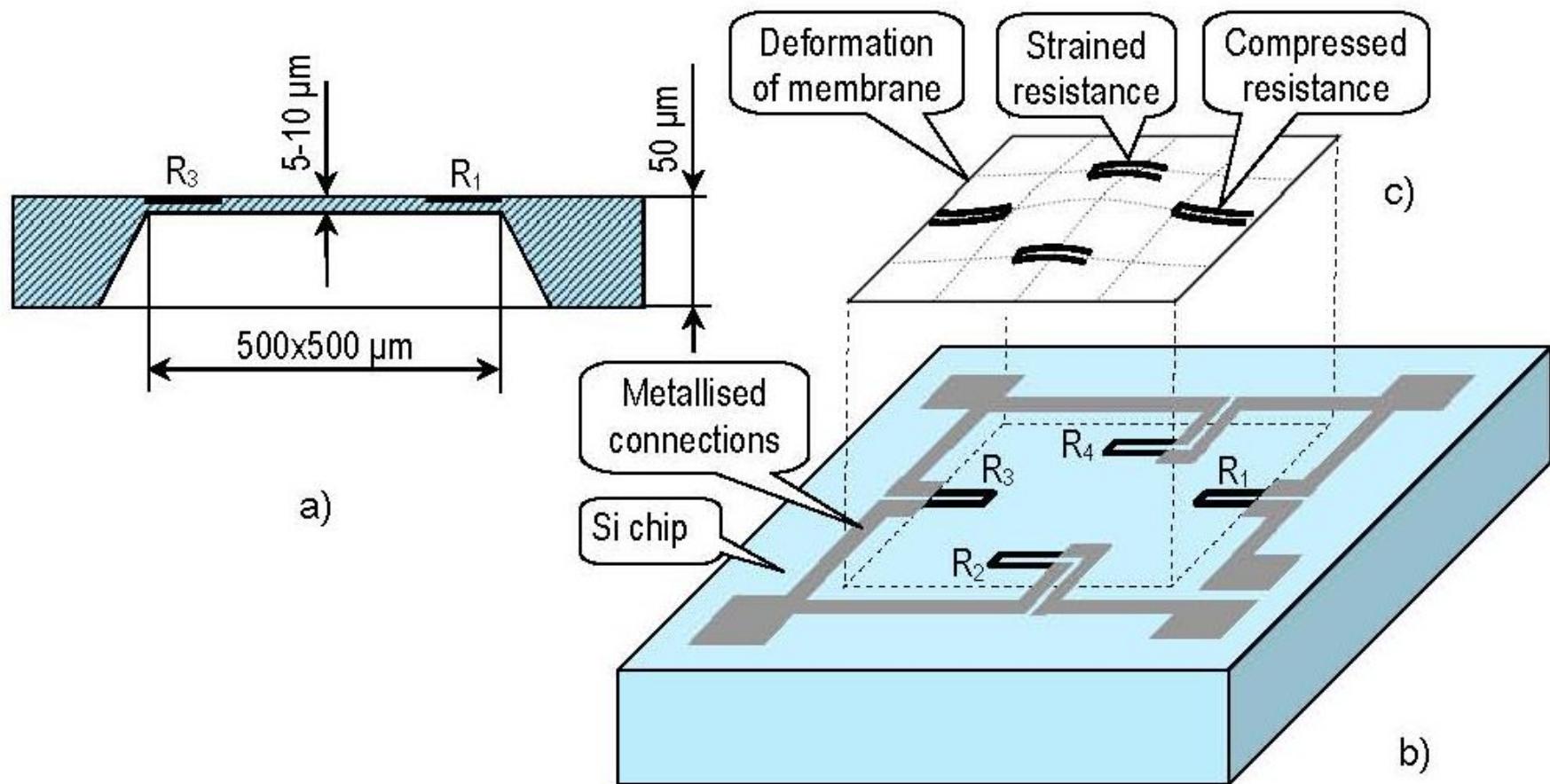
$$G = \frac{\frac{\Delta R}{R}}{\frac{\Delta L}{L}} = 2 \text{ (factor de ganancia)}$$

Determine  $V_o$  cuando se aplica una fuerza que hace que el largo de los galos aumente un 1% respecto del largo sin fuerza.

$$V_o = G \frac{\Delta L}{L} V_{cc} = 2 \frac{0.01L}{L} V_{cc} = \underline{2 \cdot 0.01 V_{cc}}$$



# Puente de Wheatstone

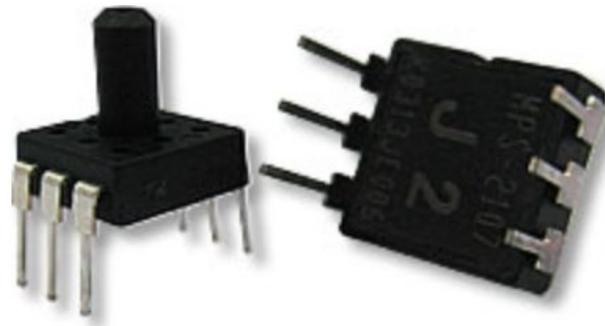


Ejemplo: MPS2100 series

# MPS-2100 Series Pressure Sensor

## Features

- Competitive price DIP package
- Wide operating temperature range: -40 to 85°C
- Solid-state reliability
- Easy to use
- Easily Embedded in OEM Equipment
- Gauge pressure type (1, 5.8, 15, 30, 100 psi)

[Datasheet](#)[MPS-2100 Series](#)

## Applications

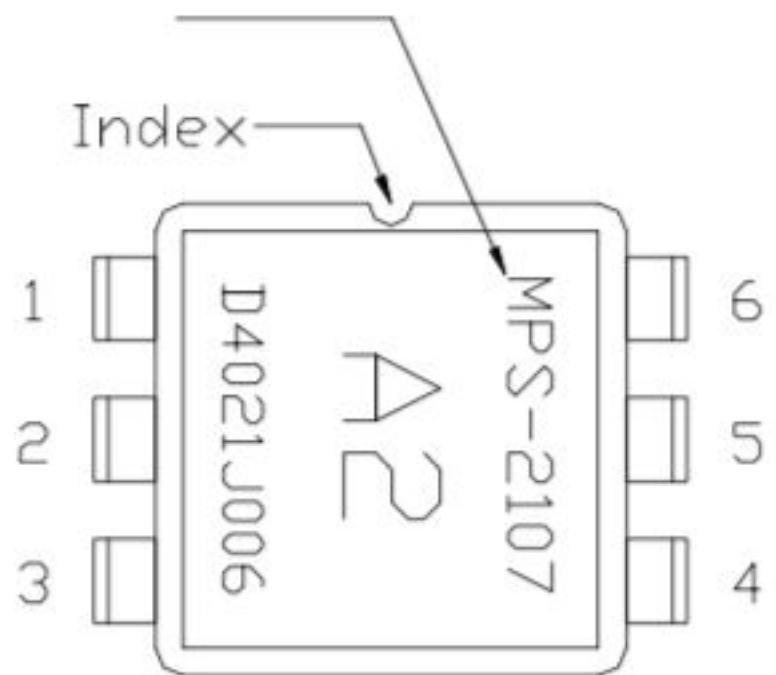
- Digital blood pressure meter
- Digital pressure gauges
- Environmental monitoring
- Consumer
- Medical instrumentation & monitoring

[RoHS compliance](#)

## Description

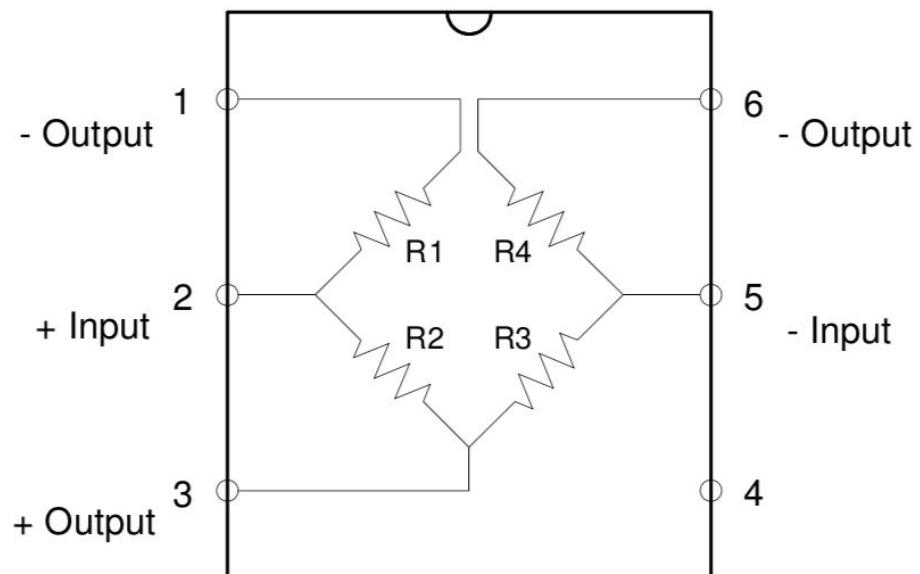
# MPS-2107-006GC

Labelled side



Pressur

## ■ Terminal connection diagram



→ R cambia en función de la temperatura

$$R = R_0 (1 + \alpha T + \beta T^2)$$

$R_0$  : Resistencia a  $0^\circ\text{C}$ .

T : Temperatura ( $^\circ\text{C}$ )

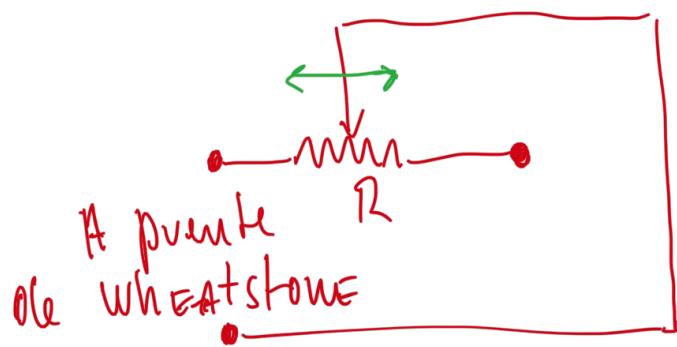
$\alpha$  : Coeficiente de temperatura  
( $> 0$  metales,  $< 0$  no metales).

$\beta$  : Coeficiente de temperatura de 2º orden.

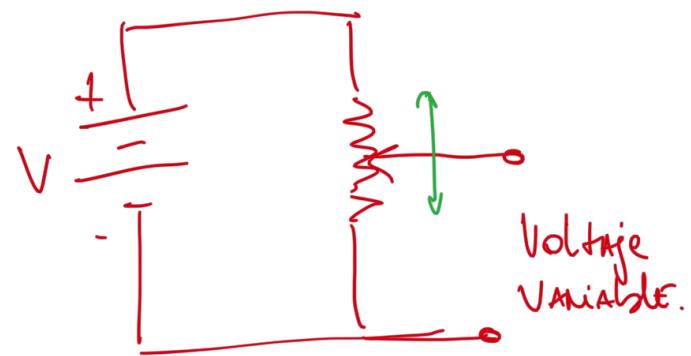
RTD ( Resistance temperature devices ) Son  
un ejemplo en esta categoría. A menudo  
se usa una Aproximación Lineal:

$$R = R_0 (1 + \alpha T)$$

## Sliding contact devices.



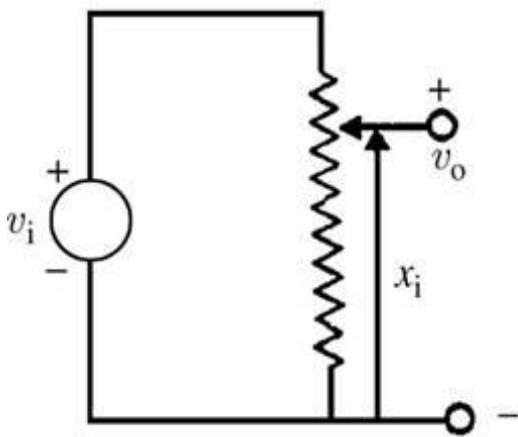
Configuración  
no sesgada



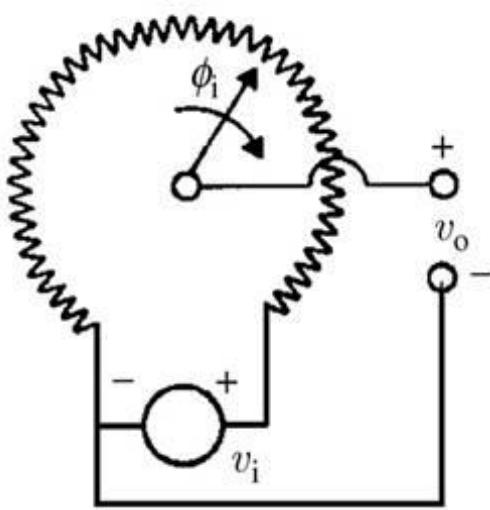
Configuración  
sesgada.

# Potenciómetros

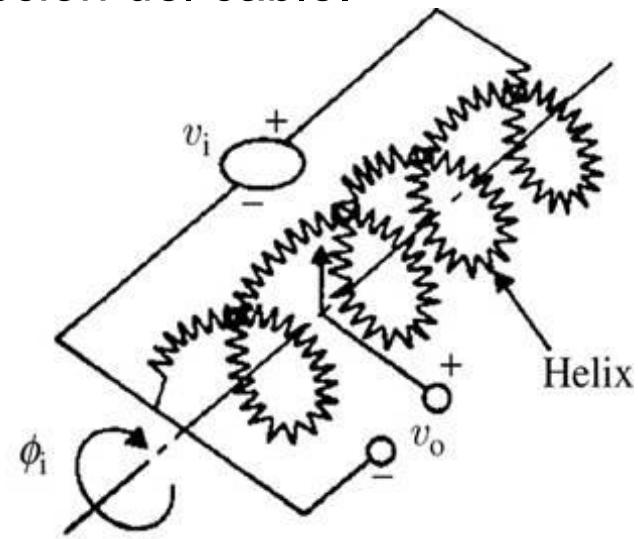
- Capaces de convertir desplazamientos lineales y angulares en un voltaje.
- 10-100 mm de desplazamiento lineal o rotación.
- La resolución es una función de la construcción del cable.



(a) Translational



(b) Single turn



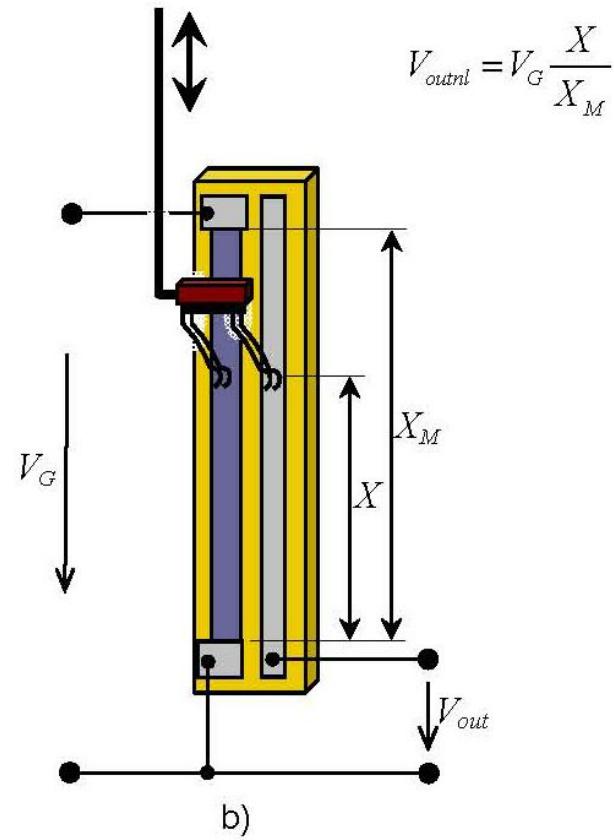
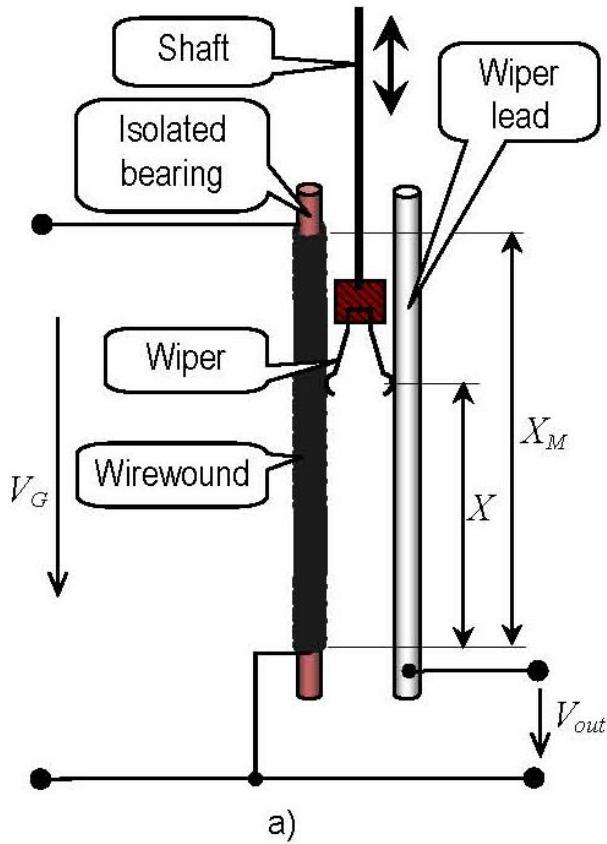
(c) Multiturn

Los potenciómetros están disponibles en el rango  $10 \Omega - 10 M\Omega$ .

Los potenciómetros usados como transductores usualmente vienen en el rango  $1 k\Omega - 100 k\Omega$ .

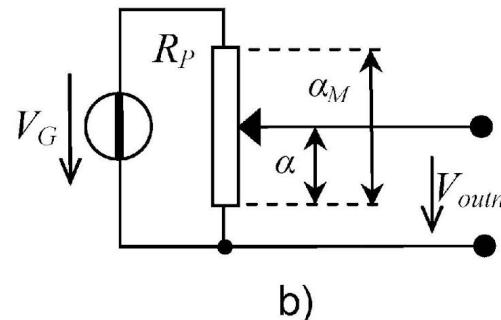
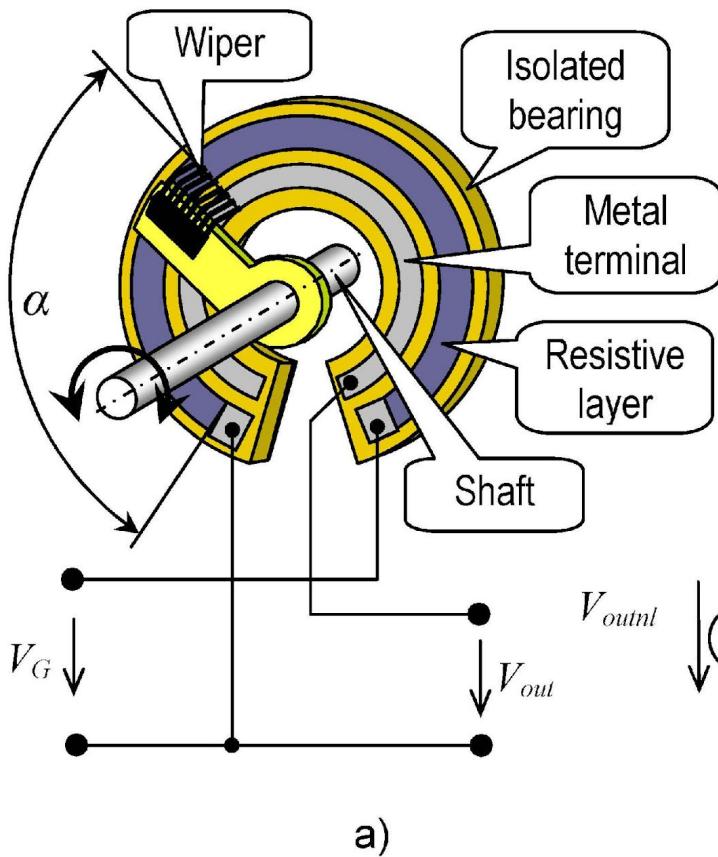
# Potenciómetros

Converting linear displacement into voltage using wire wound  
(a) and film (carbon or cermet) potentiometer (b)

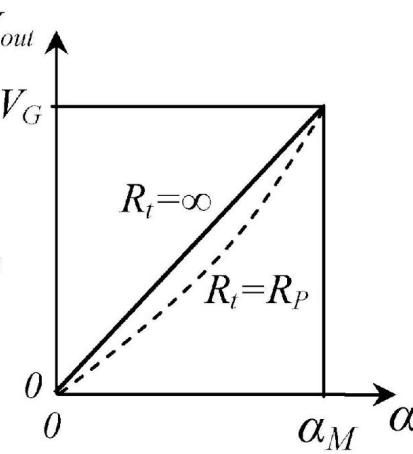
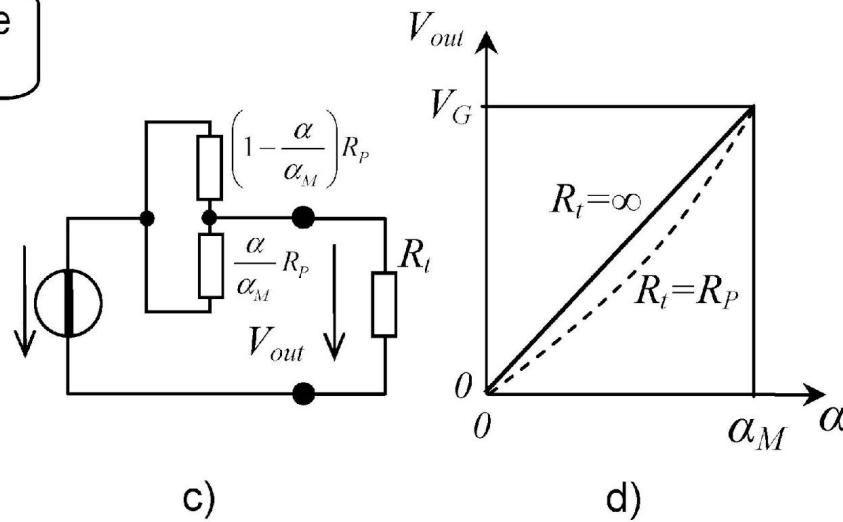


# Potenciómetros

The rotary potentiometer used as a sensor. The structure (a), symbol (b), model to calculate the loaded characteristics (c), and the transfer characteristics (d).



$$V_{outnl} = V_G \frac{\alpha}{\alpha_M} \quad (R_t = \infty)$$



# Adipómetro

